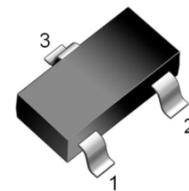


REPLACEMENT TYPE : PBSS4350T
FEATURES

- High collector current capability
- High collector current gain
- Improved efficiency due to reduced heat generation.
- Low collector-emitter saturation voltage V_{CESAT} and corresponding low R_{CESAT}



SOT-23 MARKING:ZC

1: BASE 2: Emitter 3: Collector

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value				Unit
Collector-Base Voltage	V_{CBO}	50				V
Collector-Emitter Voltage	V_{CEO}	50				V
Emitter-Base Voltage	V_{EBO}	5				V
Collector Current-Continuous	I_C	2				A
Repetitive Peak Collector Current (Note.1)	I_{CRP}	3				A
Collector Current - Pulse	I_{CP}	5				A
Base Current	I_B	0.5				A
Collector Power Dissipation	P_C	300 ^{Note2}	480 ^{Note3}	540 ^{Note4}	1.2 ^{Note1,2}	mW
Junction Temperature	T_J	150				°C
Storage Temperature	T_{stg}	-65 to 150				°C
Operating Ambient Temperature	T_{amb}	-65 to 150				°C

Notes:

1. Operated under pulsed conditions: pulse width $t_p \leq 100$ ms; duty cycle $\delta \leq 0.25$.
2. Device mounted on a printed-circuit board; single sided copper; tinplated; standard footprint.
3. Device mounted on a printed-circuit board; single sided copper; tinplated; mounting pad for collector 1 cm².
4. Device mounted on a printed-circuit board; single sided copper; tinplated; mounting pad for collector 6 cm².

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ.	Max.	Unit
Collector- Base Breakdown Voltage	V_{CBO}	$I_C=100\mu\text{A}, I_E = 0$	50			v
Collector- Emitter Breakdown Voltage	V_{CEO}	$I_C=1\text{mA}, I_B = 0$	50			v
Emitter - Base Breakdown Voltage	V_{EBO}	$I_E=100\mu\text{A}, I_C= 0$	50			v
collector-Base Cut-off Current	I_{CBO}	$V_{CB} = 50 \text{ V}; I_E = 0$			100	nA
		$V_{CB} = 50 \text{ V}; I_E = 0; T_j = 150^\circ\text{C}$			50	μA
emitter-Base Cut-off Current	I_{EBO}	$V_{EB} = 5 \text{ V}; I_C = 0$			100	nA
DC Current Gain	hFE	$V_{CE} = 2 \text{ V}; I_C = 100 \text{ mA}$	300			
		$V_{CE} = 2 \text{ V}; I_C = 500 \text{ mA}$	300			
		$V_{CE} = 2 \text{ V}; I_C = 1 \text{ A}; \text{ note 1}$	300			
		$V_{CE} = 2 \text{ V}; I_C = 2 \text{ A}; \text{ note 1}$	200			
		$V_{CE} = 2 \text{ V}; I_C = 3 \text{ A}; \text{ note 1}$	100			
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}$			80	mV
		$I_C = 1 \text{ A}; I_B = 50 \text{ mA}$			160	mV
		$I_C = 2 \text{ A}; I_B = 100 \text{ mA}; \text{ note 1}$			280	mV
		$I_C = 2 \text{ A}; I_B = 200 \text{ mA}; \text{ note 1}$			260	mV
		$I_C = 3 \text{ A}; I_B = 300 \text{ mA}; \text{ note 1}$			370	mV
Equivalent on-Resistance	$R_{CE(\text{sat})}$	$I_C = 2 \text{ A}; I_B = 200 \text{ mA}; \text{ note 1}$		100	130	$\text{m}\Omega$
Base-Emitter Saturation Voltage	$V_{BE(\text{sat})}$	$I_C = 2 \text{ A}; I_B = 100 \text{ mA}; \text{ note 1}$			1.1	V
		$I_C = 3 \text{ A}; I_B = 300 \text{ mA}; \text{ note 1}$			1.2	V
Base-Emitter Turn-on Voltage	$V_{BE(\text{on})}$	$V_{CE} = 2 \text{ V}; I_C = 1 \text{ A}; \text{ note 1}$	1.2			V
Transition Frequency	f_T	$I_C = 100 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz}$	100			MHz
Collector Capacitance	C_c	$V_{CB} = 10 \text{ V}; I_E = I_e = 0; f = 1 \text{ MHz}$			25	pF

Note 1. Pulse test: $t_p \leq 300 \mu\text{s}; \delta \leq 0.02$.

Typical Characteristics

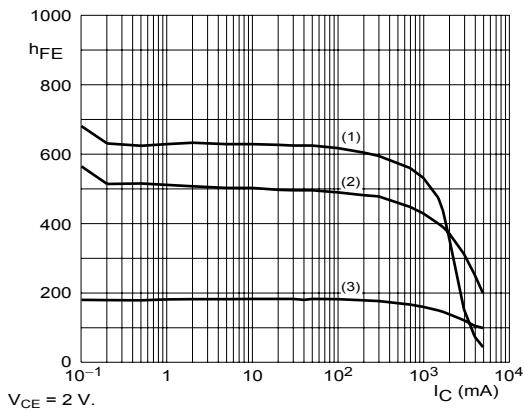


Fig.1 DC current gain as a function of collector current; typical values.
 $V_{CE} = 2 \text{ V}$.
(1) $T_{amb} = 150 \text{ }^{\circ}\text{C}$. (2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$. (3) $T_{amb} = -55 \text{ }^{\circ}\text{C}$.

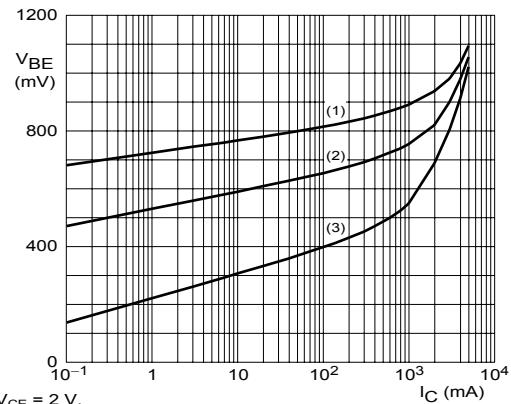


Fig.2 Base-emitter voltage as a function of collector current; typical values.
 $V_{CE} = 2 \text{ V}$.
(1) $T_{amb} = -55 \text{ }^{\circ}\text{C}$. (2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$. (3) $T_{amb} = 150 \text{ }^{\circ}\text{C}$.

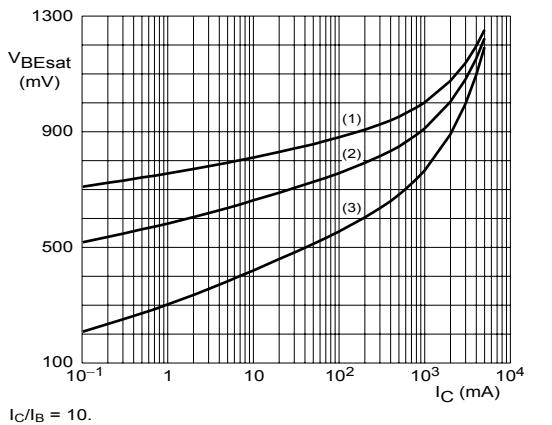


Fig.3 Base-emitter saturation voltage as a function of collector current; typical values.
 $I_C/I_B = 10$.
(1) $T_{amb} = -55 \text{ }^{\circ}\text{C}$. (2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$. (3) $T_{amb} = 150 \text{ }^{\circ}\text{C}$.

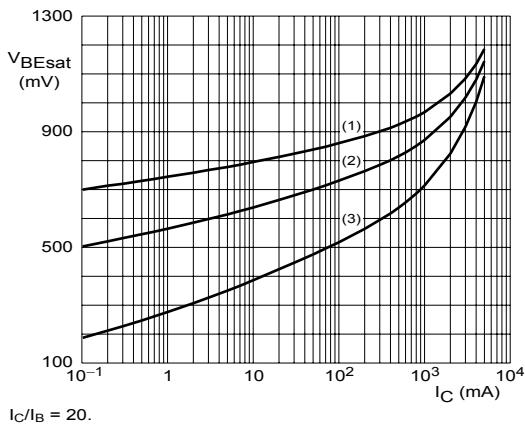


Fig.4 Base-emitter saturation voltage as a function of collector current; typical values.
 $I_C/I_B = 20$.
(1) $T_{amb} = -55 \text{ }^{\circ}\text{C}$. (2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$. (3) $T_{amb} = 150 \text{ }^{\circ}\text{C}$.

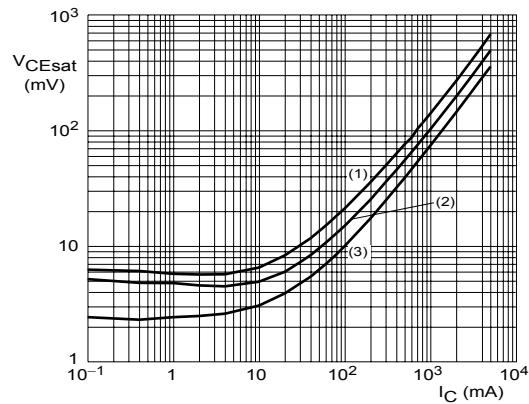


Fig.5 Collector-emitter saturation voltage as a function of collector current; typical values.
 $I_C/I_B = 10$.
(1) $T_{amb} = 150 \text{ }^{\circ}\text{C}$. (2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$. (3) $T_{amb} = -55 \text{ }^{\circ}\text{C}$.

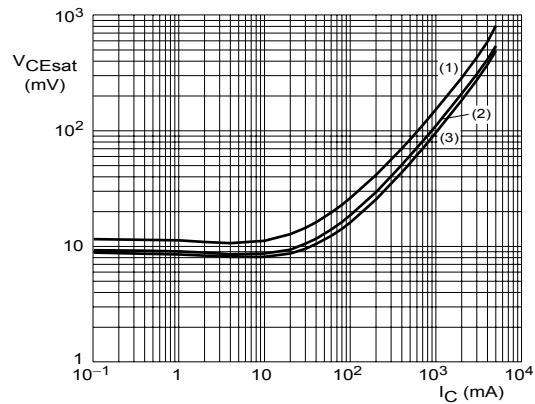
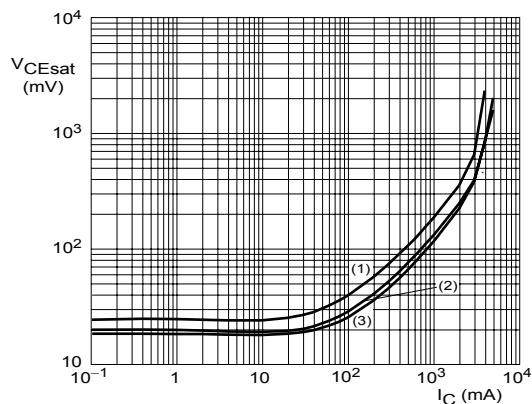


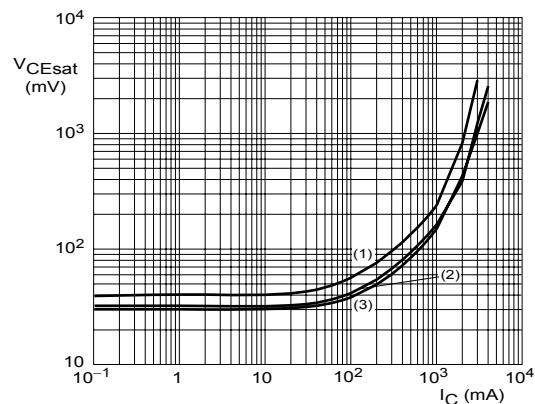
Fig.6 Collector-emitter saturation voltage as a function of collector current; typical values.
 $I_C/I_B = 20$.
(1) $T_{amb} = 150 \text{ }^{\circ}\text{C}$. (2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$. (3) $T_{amb} = -55 \text{ }^{\circ}\text{C}$.

Typical Characteristics



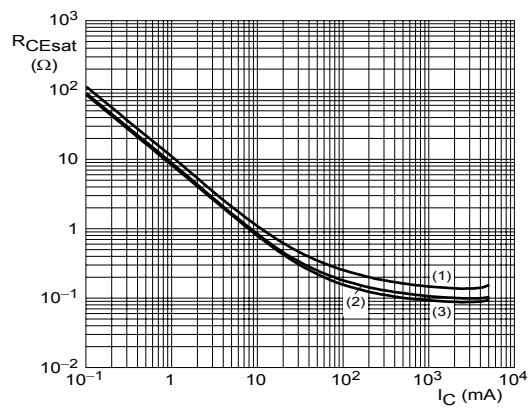
$I_C/I_B = 50$.
(1) $T_{amb} = 150 \text{ } ^\circ\text{C}$. (2) $T_{amb} = 25 \text{ } ^\circ\text{C}$. (3) $T_{amb} = -55 \text{ } ^\circ\text{C}$.

Fig.7 Collector-emitter saturation voltage as a function of collector current; typical values.



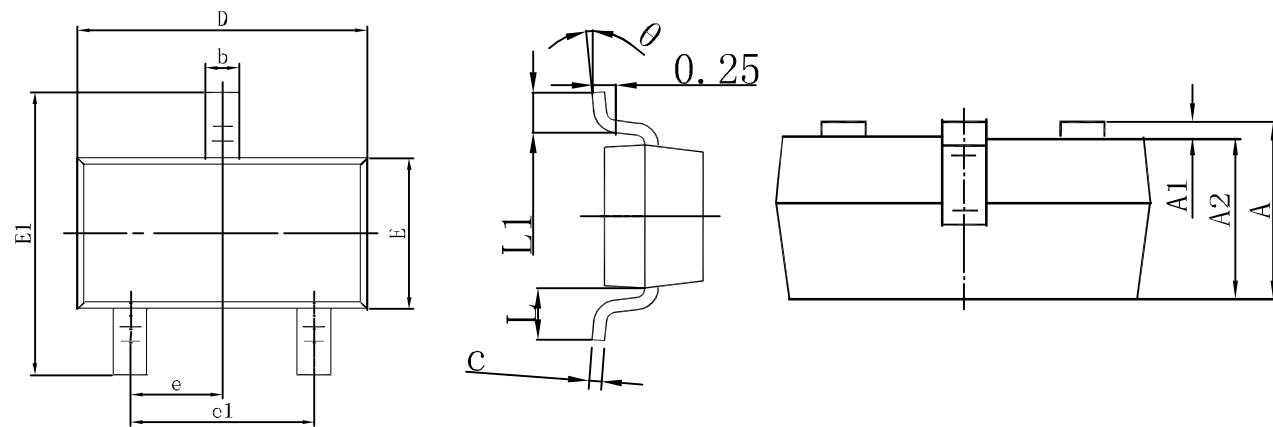
$I_C/I_B = 100$.
(1) $T_{amb} = 150 \text{ } ^\circ\text{C}$. (2) $T_{amb} = 25 \text{ } ^\circ\text{C}$. (3) $T_{amb} = -55 \text{ } ^\circ\text{C}$.

Fig.8 Collector-emitter saturation voltage as a function of collector current; typical values.

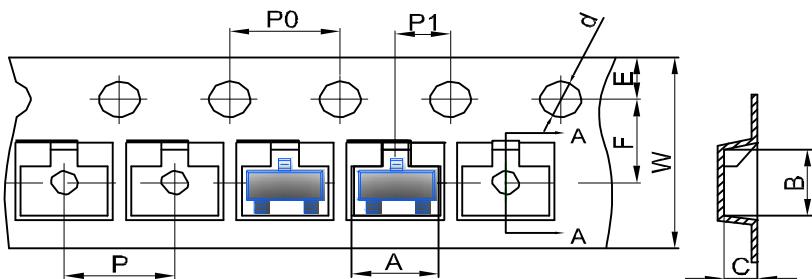


$I_C/I_B = 20$.
(1) $T_{amb} = 150 \text{ } ^\circ\text{C}$. (2) $T_{amb} = 25 \text{ } ^\circ\text{C}$. (3) $T_{amb} = -55 \text{ } ^\circ\text{C}$.

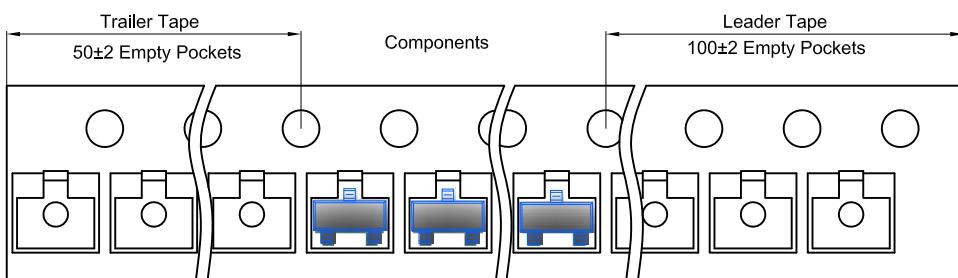
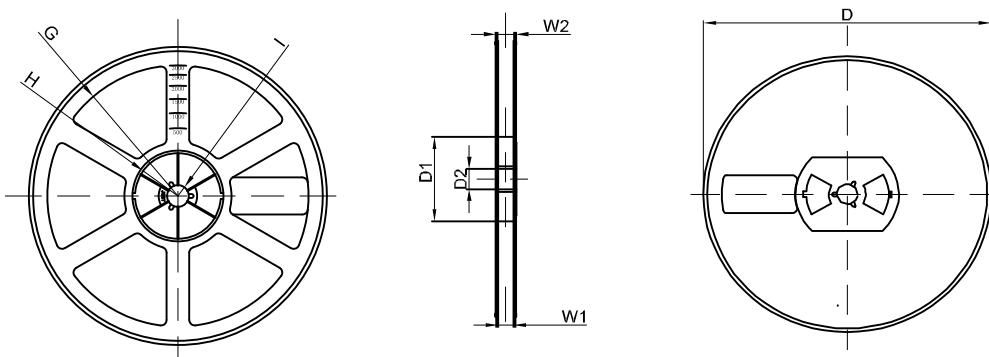
Fig.10 Equivalent on-resistance as a function of collector current; typical values.

SOT-23 Package Outline Dimensions


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Embossed Carrier Tape


TYPE	DIMENSIONS ARE IN MILLIMETER									
	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	φ1.50	1.75	3.50	4.00	4.00	2.00	8.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SOT-23 Tape Leader and Trailing

SOT-23 Reel


REEL OPTION	DIMENSIONS ARE IN MILLIMETER								
	D	D1	D2	G	H	I	W1	W2	
7" DIA	φ178	54.40	13.00	R78	R25.60	R6.50	9.50	12.30	
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1	